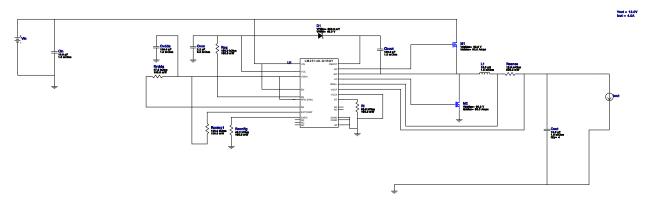
VinMin = 24.0V VinMax = 35.0V Vout = 12.0V Iout = 4.0A Device = LM25148QRGYRQ1 Topology = Buck Created = 2023-08-09 03:28:50.025 BOM Cost = \$5.40 BOM Count = 19 Total Pd = 1.23W

WEBENCH® Design Report

Design: 8 LM25148QRGYRQ1 LM25148QRGYRQ1 24V-35V to 12.00V @ 4A



Design Alerts

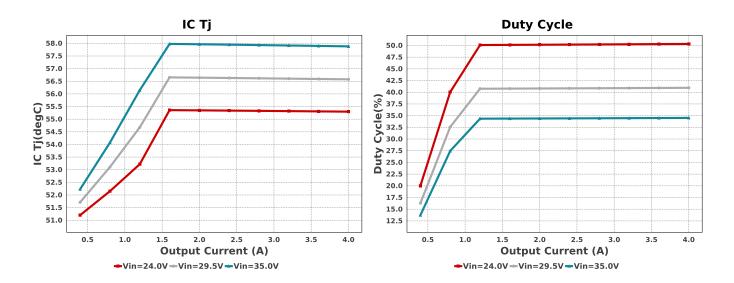
Component Selection Information

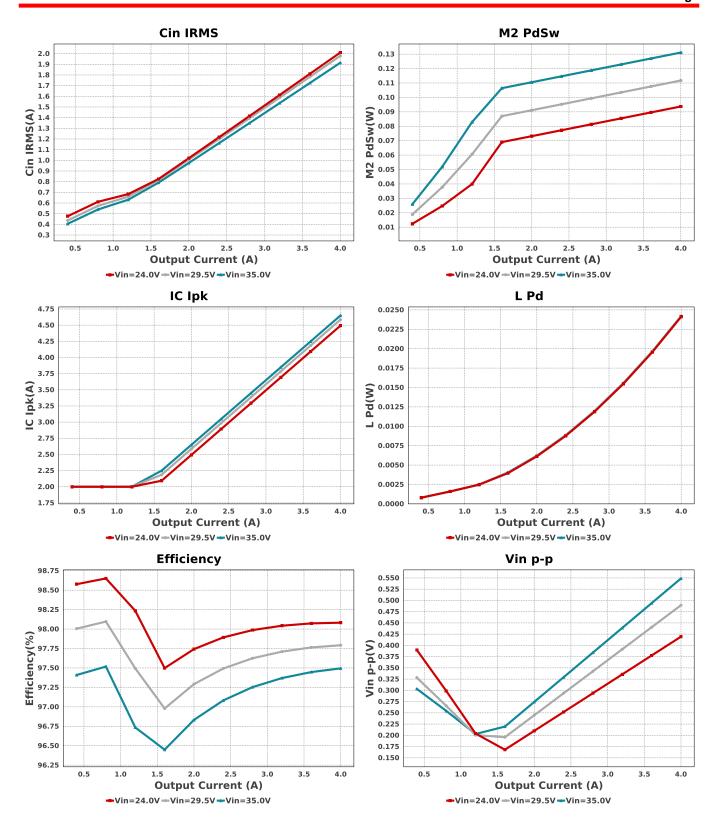
The LM25148-Q1 is qualified for Automotive applications. All passives and other components selected in this design may not be qualified for Automotive applications. The user is required to verify that all components in the design meet the qualification and safety requirements for their specific application.

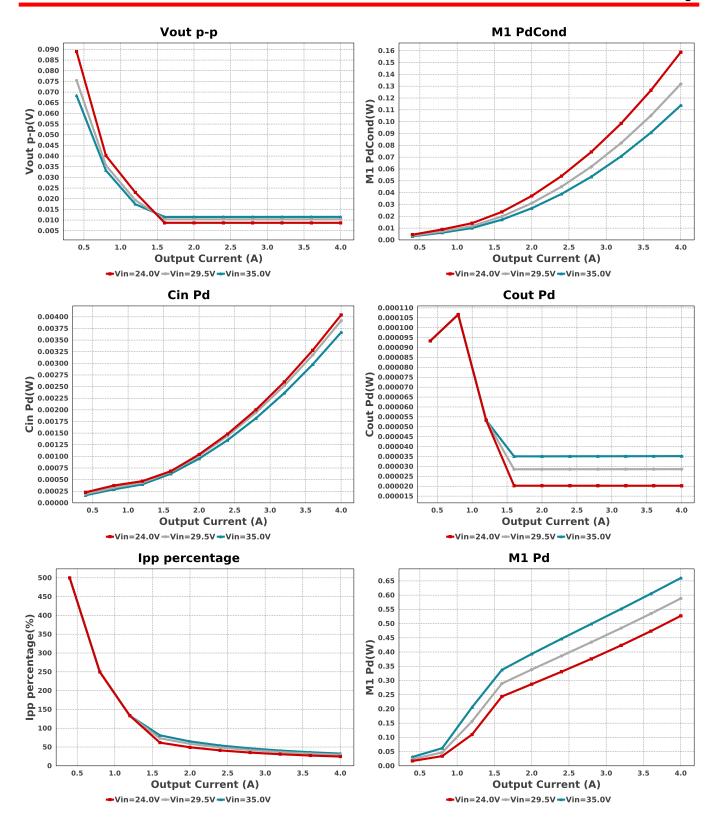
Electrical BOM

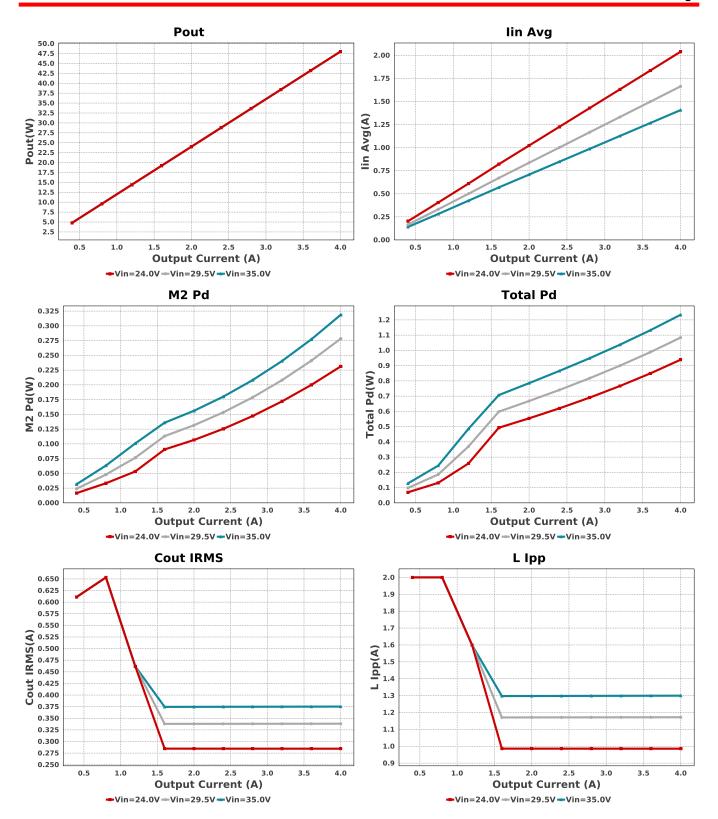
Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
Cboot	MuRata	GRM155R71A104KA01D Series= X7R	Cap= 100.0 nF ESR= 1.0 mOhm VDC= 10.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm ²
Cin	MuRata	GRM32ER71J106KA12L Series= X7R	Cap= 10.0 uF ESR= 1.0 mOhm VDC= 63.0 V IRMS= 6.0 A	1	\$0.30	1210_280 15 mm ²
Cout	TDK	C3225X7R1H106M250AC Series= X7R	Cap= 10.0 uF ESR= 1.0 mOhm VDC= 50.0 V IRMS= 5.0 A	4	\$0.27	1210 15 mm ²
Cvcc	MuRata	GRM188R71A225KE15D Series= X7R	Cap= 2.2 uF ESR= 9.0 mOhm VDC= 10.0 V IRMS= 3.3 A	1	\$0.02	0603 5 mm ²
Cvdda	MuRata	GRM155R71A104KA01D Series= X7R	Cap= 100.0 nF ESR= 1.0 mOhm VDC= 10.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm ²
D1	Vishay-Semiconductor	BYS10-45-E3/TR	VF@Io= 500.0 mV VRRM= 45.0 V	1	\$0.11	SMA 37 mm ²

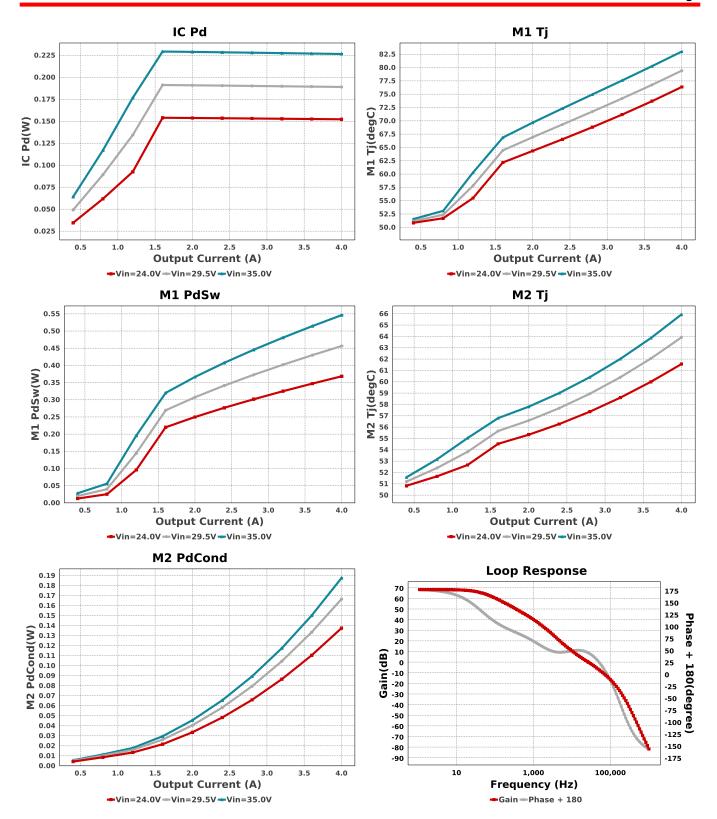
Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
L1	Coilcraft	SER2915L-153KL	L= 15.0 μH 1.5 mOhm	1	\$1.88	
M1	Texas Instruments	CSD18534Q5A	VdsMax= 60.0 V	1	\$0.31	SER2915L 652 mm ²
IVII	rexas instruments	COD 10004Q0A	IdsMax= 50.0 Amps	'	ψ0.51	
						DQJ0008A 55 mm ²
M2	Texas Instruments	CSD18534Q5A	VdsMax= 60.0 V IdsMax= 50.0 Amps	1	\$0.31	
						DQJ0008A 55 mm ²
Rcomp1	Vishay-Dale	CRCW0603100KFKEA Series= CRCWe3	Res= 100.0 kOhm Power= 100.0 mW Tolerance= 1.0%	1	\$0.01	0603 5 mm ²
Rconfig	Vishay-Dale	CRCW060340K2FKEA Series= CRCWe3	Res= 40.2 kOhm Power= 100.0 mW Tolerance= 1.0%	1	\$0.01	0603 5 mm ²
Rpg	Vishay-Dale	CRCW0603100KFKEA Series= CRCWe3	Res= 100.0 kOhm Power= 100.0 mW Tolerance= 1.0%	1	\$0.01	0603 5 mm ²
Rsense	Stackpole Electronics Inc	CSR1206FK12L0 Series= ?	Res= 12.0 mOhm Power= 500.0 mW Tolerance= 1.0%	1	\$0.11	1206 11 mm ²
Rt	Vishay-Dale	CRCW060353K6FKEA Series= CRCWe3	Res= 53.6 kOhm Power= 100.0 mW Tolerance= 1.0%	1	\$0.01	0603 5 mm ²
Rvdda	Vishay-Dale	CRCW060347K5FKEA Series= CRCWe3	Res= 47.5 kOhm Power= 100.0 mW Tolerance= 1.0%	1	\$0.01	0603 5 mm ²
U1	Texas Instruments	LM25148QRGYRQ1	Switcher	1	\$1.21	DOV0004E MEG 402
						RGY0024E-MFG 48 mm ²

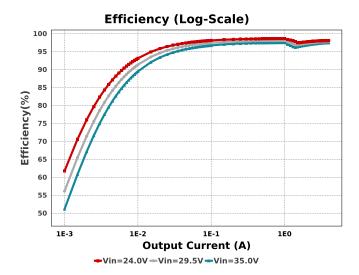












Operating Values

-				
#	Name	Value	Category	Description
1.	Cin IRMS	1.914 A	Capacitor	Input capacitor RMS ripple current
2.	Cin Pd	3.665 mW	Capacitor	Input capacitor power dissipation
3.	Cout IRMS	375.169 mA	Capacitor	Output capacitor RMS ripple current
4.	Cout Pd	35.188 μW	Capacitor	Output capacitor power dissipation
5.	IC lpk	4.65 A	IC '	Peak switch current in IC
6.	IC Pd	226.48 mW	IC	IC power dissipation
7.	IC Tj	57.881 degC	IC	IC junction temperature
8.	IC Tolerance	120.0 mV	IC	IC Feedback Tolerance
9.	ICThetaJA Effective	34.8 degC/W	IC	Effective IC Junction-to-Ambient Thermal Resistance
10.	lin Avg	1.407 A	IC	Average input current
11.	lpp percentage	32.491 %	Inductor	Inductor ripple current percentage (with respect to average inductor current)
12.	L lpp	1.3 A	Inductor	Peak-to-peak inductor ripple current
	L Pd	24.211 mW	Inductor	Inductor power dissipation
	M1 Pd	660.14 mW	Mosfet	M1 MOSFET total power dissipation
15.	M1 PdCond	113.75 mW	Mosfet	M1 MOSFET conduction losses
16.	M1 PdSw	546.39 mW	Mosfet	M1 MOSFET switching losses
17.	M1 Tj	83.007 degC	Mosfet	M1 MOSFET junction temperature
18.	M2 Pd	318.67 mW	Mosfet	M2 MOSFET total power dissipation
19.	M2 PdCond	187.56 mW	Mosfet	M2 MOSFET conduction losses
20.	M2 PdSw	131.11 mW	Mosfet	M2 MOSFET switching losses
21.	M2 Tj	65.934 degC	Mosfet	M2 MOSFET junction temperature
22.	Cin Pd	3.665 mW	Power	Input capacitor power dissipation
23.	Cout Pd	35.188 μW	Power	Output capacitor power dissipation
24.	IC Pd	226.48 mW	Power	IC power dissipation
25.	L Pd	24.211 mW	Power	Inductor power dissipation
26.	M1 Pd	660.14 mW	Power	M1 MOSFET total power dissipation
27.	M1 PdCond	113.75 mW	Power	M1 MOSFET conduction losses
28.	M1 PdSw	546.39 mW	Power	M1 MOSFET switching losses
29.	M2 Pd	318.67 mW	Power	M2 MOSFET total power dissipation
30.	M2 PdCond	187.56 mW	Power	M2 MOSFET conduction losses
31.	M2 PdSw	131.11 mW	Power	M2 MOSFET switching losses
32.	Total Pd	1.233 W	Power	Total Power Dissipation
33.	BOM Count	19	System	Total Design BOM count
			Information	
34.	Cross Freq	26.49 kHz	System	Bode plot crossover frequency
c-	D . O .	04.540.0/	Information	
35.	Duty Cycle	34.516 %	System	Duty cycle
	F.(: :	07.405.0/	Information	
36.	Efficiency	97.495 %	System	Steady state efficiency
27	ContDrint	200.0	Information	Total Foot Print Area of DOM components
37.	FootPrint	966.0 mm ²	System	Total Foot Print Area of BOM components
38.	Eroguonov	405.68 kHz	Information	Switching frequency
30.	Frequency	400.00 KHZ	System Information	Switching frequency
39.	Gain Marg	-13.788 dB	System	Bode Plot Gain Margin
	-	-	Information	- · · · · · · · · · · · · · · · · · · ·
40.	lout	4.0 A	System	lout operating point
			Information	
41.	lout transient step use	ed 2.0 A	System	Custom Transient current step requirement that was used for Cout
	for Cout calculations		Information	selection (A).
				• /

#	Name	Value	Category	Description
42.	Low Freq Gain	68.231 dB	System	Gain at 1Hz
			Information	
43.	Mode	CCM	System	Conduction Mode
44.	Overshoot Value	71.766 mV	Information System	Theoretical Vout Overshoot Value
44.	Overshoot value	71.7001110	Information	Theoretical vout Overshoot value
45.	Phase Marg	46.29 deg	System	Bode Plot Phase Margin
	· ·	· ·	Information	Č
46.	Pout	48.0 W	System	Total output power
	T	^- .	Information	T
47.	Total BOM	\$5.4	System Information	Total BOM Cost
48.	Undershoot Value	130.444 mV	System	Theoretical Vout Undershoot Value
₹0.	Ondershoot value	100.444 1111	Information	Theoretical vout officershoot value
49.	Vin	35.0 V	System	Vin operating point
			Information	
50.	Vin p-p	548.885 mV	System	Peak-to-peak input voltage
			Information	
51.	Vout	12.0 V	System Information	Operational Output Voltage
52.	Vout Ripple	1.0 %	System	Custom maximum output ripple requirement that was used for Cout
JZ.	requirement used for	1.0 /0	Information	selection(% of Vout).
	Cout calculations		momation	oblocker (70 dr Voul).
53.	Vout Tolerance	1.0 %	System	Vout Tolerance based on IC Tolerance (no load) and voltage divider
			Information	resistors if applicable
54.	Vout p-p	11.498 mV	System	Peak-to-peak output ripple voltage
		0.00/	Information	
55.	Vout transient	3.0 %	System	Custom Transient voltage change requirement that was used for Cout
	requirement used for Cout calculations		Information	selection (% of Vout).
	Cout calculations			

Design Inputs

9 1			
Name	Value	Description	
lout	4.0	Maximum Output Current	
VinMax	35.0	Maximum input voltage	
VinMin	24.0	Minimum input voltage	
Vout	12.0	Output Voltage	
base_pn	LM25148-Q1	Base Product Number	
source	DC	Input Source Type	
Ta	50.0	Ambient temperature	
UserFsw	2.075 M	Customer Selected Frequency	

WEBENCH® Assembly

Component Testing

Some published data on components in datasheets such as Capacitor ESR and Inductor DC resistance is based on conservative values that will guarantee that the components always exceed the specification. For design purposes it is usually better to work with typical values. Since this data is not always available it is a good practice to measure the Capacitance and ESR values of Cin and Cout, and the inductance and DC resistance of L1 before assembly of the board. Any large discrepancies in values should be electrically simulated in WEBENCH to check for instabilities and thermally simulated in WebTHERM to make sure critical temperatures are not exceeded.

Soldering Component to Board

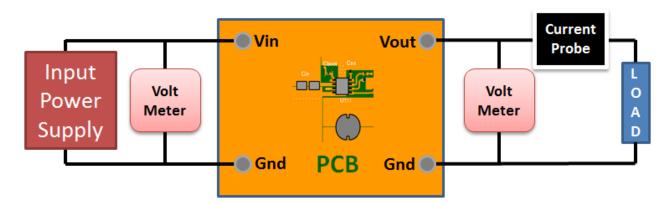
If board assembly is done in house it is best to tack down one terminal of a component on the board then solder the other terminal. For surface mount parts with large tabs, such as the DPAK, the tab on the back of the package should be pre-tinned with solder, then tacked into place by one of the pins. To solder the tab town to the board place the iron down on the board while resting against the tab, heating both surfaces simultaneously. Apply light pressure to the top of the plastic case until the solder flows around the part and the part is flush with the PCB. If the solder is not flowing around the board you may need a higher wattage iron (generally 25W to 30W is enough).

Initial Startup of Circuit

It is best to initially power up the board by setting the input supply voltage to the lowest operating input voltage 24.0V and set the input supply's current limit to zero. With the input supply off connect up the input supply to Vin and GND. Connect a digital volt meter and a load if needed to set the minimum lout of the design from Vout and GND. Turn on the input supply and slowly turn up the current limit on the input supply. If the voltage starts to rise on the input supply continue increasing the input supply current limit while watching the output voltage. If the current increases on the input supply, but the voltage remains near zero, then there may be a short or a component misplaced on the board. Power down the board and visually inspect for solder bridges and recheck the diode and capacitor polarities. Once the power supply circuit is operational then more extensive testing may include full load testing, transient load and line tests to compare with simulation results.

Load Testing

The setup is the same as the initial startup, except that an additional digital voltmeter is connected between Vin and GND, a load is connected between Vout and GND and a current meter is connected in series between Vout and the load. The load must be able to handle at least rated output power + 50% (7.5 watts for this design). Ideally the load is supplied in the form of a variable load test unit. It can also be done in the form of suitably large power resistors. When using an oscilloscope to measure waveforms on the prototype board, the ground leads of the oscilloscope probes should be as short as possible and the area of the loop formed by the ground lead should be kept to a minimum. This will help reduce ground lead inductance and eliminate EMI noise that is not actually present in the circuit.



Design Assistance

- 1. Master key: 18357C3A6FC010F679187DF770631ECB[v1]
- 2. LM25148-Q1 Product Folder: http://www.ti.com/product/LM25148%2DQ1: contains the data sheet and other resources.

Important Notice and Disclaimer

TI provides technical and reliability data (including datasheets), design resources (including reference designs), application or other design advice, web tools, safety information, and other resources AS IS and with all faults, and disclaims all warranties. These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

Providing these resources does not expand or otherwise alter TI's applicable Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with TI products.